

L Number	Hits	Search Text	DB	Time stamp
1	61332	(thin near film near transistor) TFT	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/12 10:25
2	193668	gate and ((source and drain) source/drain)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/12 10:26
3	21918	((thin near film near transistor) TFT) and (gate and ((source and drain) source/drain))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/12 10:27
4	1966169	substrate wafer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/12 10:27
5	18741	((thin near film near transistor) TFT) and (gate and ((source and drain) source/drain))) and (substrate wafer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/12 10:28
6	5354	((thin near film near transistor) TFT) and (gate and ((source and drain) source/drain))) and (substrate wafer)) and organic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/12 10:29
9	85844	dielectric near2 constant	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/12 10:30
10	1163	((thin near film near transistor) TFT) and (gate and ((source and drain) source/drain))) and (substrate wafer)) and organic) and (dielectric near2 constant)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/12 10:30